Features

- Floating channel designed for bootstrap operation.
- Fully operational up to +600V
- Tolerant to negative transient voltage, dV/dt immune
- Gate drive supply range from 10V to 20V
- Independent low and high side channels.
- Input logic HIN/LIN active high
- Undervoltage lockout for both channels
- 3.3V, 5V, and 15V input logic compatible
- CMOS Schmitt-triggered inputs with pull-down
- Matched propagation delay for two channels
- Lead-Free and RoHS Compliant
- Automotive qualified*

Typical Applications

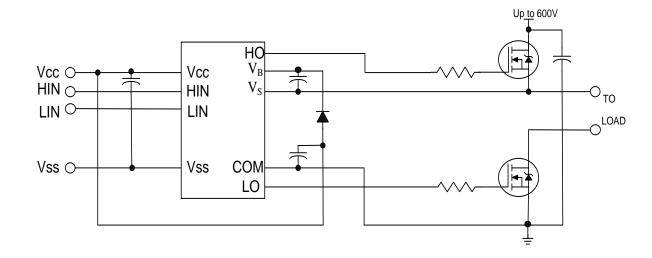
- Automotive AC/DC and DC/DC converters
- High power DC-DC SMPS converters
- Other high frequency applications

Typical Connection Diagram

Product Summary	
V _{OFFSET}	≤ 600V
V _{OUT}	10 – 20V
l₀₊ & l ₀₋ (typical)	3.5A & 3.5A
t _{ON} & t _{OFF} (typical)	90ns & 90ns
Delay Matching (max)	25ns

Package Options





(Refer to Lead Assignments for correct pin configuration). This/These diagram(s) show electrical connections only. Please refer to our Application Notes and Design Tips for proper circuit board layout.



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Description

The AUIRS2191S is a high power, high voltage, high speed power MOSFET and IGBT driver with independent high and low side referenced output channels, designed for Automotive AC/DC and DC/DC converter applications. Logic inputs are compatible with standard CMOS or LSTTL output, down to 3.3V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. Propagation delays are matched to simplify use in high frequency applications. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 600V. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction.



Qualification Information[†]

		Automotive (per AEC-Q100 ^{††})			
Unanneation Level		Comments: This family of ICs has passed an Automotiv qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotiv			
		level.			
Moisture Sensitivity Level		MSL3 ^{††} 260°C (per IPC/JEDEC J-STD-020)			
	Machine Model	Class M1 (100V) (per AEC-Q100-003)			
ESD	Human Body Model	Class H1B (1000V) (per AEC-Q100-002)			
Charged Device Model		Class C4 (1000V) (per AEC-Q100-011)			
IC Latch-Up Test		Class II Level A			
-					
IC Latch-Up Test RoHS Compliant		Class II Level A (per AEC-Q100-004) Yes			

† Qualification standards can be found at International Rectifier's web site http://www.irf.com/

++ Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information.



Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which permanent damage to the device may occur. These are stress ratings only, functional operation of the device at these or any other condition beyond those indicated in the "Recommended Operating Condition" is not implied. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability. All voltage parameters are absolute voltages referenced to COM unless otherwise stated in the table. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min	Max	Units
V _B	High side floating supply voltage	-0.3	620	
Vs	High side floating supply offset voltage	$V_B - 20$	V _B + 0.3	
V _{HO}	High side floating output voltage	$V_{S} - 0.3$	V _B +0.3	
V _{CC}	Low side fixed supply voltage	-0.3	20	V
V _{LO}	Low-side output voltage	-0.3	V _{CC} + 0.3	
V _{IN}	Logic input voltage (HIN & LIN)	$V_{SS} - 0.3$	V _{CC} + 0.3	
V _{SS}	Logic ground	$V_{CC} - 20$	V _{CC} + 0.3	
dV _S /dt	Allowable V _S offset supply transient		50	V/ns
PD	Package power dissipation @ T _A ≤+25 ⁰C		1.0	W
R _{OJA}	Thermal resistance, junction to ambient		100	°C/W
TJ	Junction temperature		150	
Ts	Storage temperature	-55	150	°C
TL	Lead temperature (soldering, 10 seconds)		300	

Recommended Operating Conditions

The input/output logic timing diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions. The VS, VSS, and COM offset ratings are tested with all supplies biased at 15V differential.

Symbol	Definition	Min	Max	Units
V _B	High side floating supply absolute voltage	V _S + 10	V _S + 20	
Vs	High side floating supply offset voltage	+	600	
V _{HO}	High side floating output voltage	Vs	V _B	V
V _{CC}	Low side fixed supply voltage	10	20	
V _{LO}	Low side output voltage	0	V _{cc}	
V _{IN}	Logic input voltage (HIN & LIN)	V _{SS}	V _{CC}	
V _{SS}	Logic ground	-5	5	
T _A	Ambient temperature	-40	125	°C

[†] Logic operation for V_S of -5 V to 600 V. Logic state held for V_S of -5 V to $-V_{BS}$. (Please refer to Design Tip DT97-3 for more details)



Static Electrical Characteristics

Unless otherwise noted, these specifications apply for an operating junction temperature range of $-40^{\circ}C \le Tj \le 125^{\circ}C$ with bias conditions of V_{BIAS} (VCC or VBS) = 15V. The VIN, VTH parameters are referenced to VSS and are applicable to all logic input leads: HIN and LIN. The VO parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

Symbol	Definition		Тур	Max	Unit s	Test Conditions
V _{IH}	Logic "1" input voltage	2.5				
V _{IL}	Logic "0" input voltage			0.8		$V_{CC} = 9.8V - 20V$
V _{OH 2mA}	High level output voltage, V _{BIAS} -V _O			2.5	V	I _o = 2 mA
V _{OH 20mA}				3.3		l _o = 20 mA
V _{OL}	Low level output voltage, Vo			0.1		I _o = 2 mA
I _{LK}	Offset supply leakage current			50		$V_{B} = V_{S} = 600 V$
I _{QBS}	Quiescent V _{BS} supply current		100	200		$V_{IN} = 0V \text{ or } 3.3V$
I _{QCC}	Quiescent V _{CC} supply current		150	300		$V_{IN} = 0V \text{ or } 3.3V$
I _{QBS18}	Quiescent V _{BS} supply current		180	300		V _{IN} = 0V or 3.3V V _{BS} =18V
I _{QCC18}	Quiescent V_{CC} supply current		300	450	μA	$V_{IN} = 0V \text{ or } 3.3V$ $V_{CC} = 18V$
I _{QBS20}	Quiescent V _{BS} supply current		850	1500		$V_{IN} = 0V \text{ or } 3.3V$ $V_{BS} = 20V$
I _{QCC20}	Quiescent V_{CC} supply current		1500	2500		$V_{IN} = 0V \text{ or } 3.3V$ $V_{CC} = 20V$
I _{IN+}	Logic "1" input bias current		3.5	7		$V_{IN} = 3.3V$
I _{IN-}	Logic "0" input bias current			1.0		$V_{IN} = 0V$
V _{BSUV+}	V_{BS} supply undervoltage positive going threshold	8.0	8.9	9.8		
V _{BSUV-}	V _{BS} supply undervoltage negative going threshold	7.4	8.2	8.8		
V _{BSUVHYS}	V _{BS} supply undervoltage hysteresis	0.3	0.7		v	
V _{CCUV+}	V _{CC} supply undervoltage positive going threshold	8.0	8.9	9.8	v	
V _{CCUV} -	V _{CC} supply undervoltage negative going threshold	7.4	8.2	9.0		
V _{CCUVHYS}	V _{cc} supply undervoltage hysteresis	0.3	0.7			
I _{O+}	D+ Output high short circuit pulsed current ^(†)		3.5		A	V _O = 0 V, PW ≤ 10 µs, Tj = 25°C
I _{O-}			3.5			V _O = 15 V, PW ≤ 10 µs Tj = 25°C
I _{O+}	Output high short circuit pulsed current ^(†)		3.5		А	V _O = 0 V, PW ≤ 10 μs,
I _{O-}	Output low short circuit pulsed current ^(†)	1.8	3.5			V _O = 15 V, PW ≤ 10 µs

^(†) Guaranteed by design

Dynamic Electrical Characteristics

Unless otherwise noted, these specifications apply for an operating junction temperature range of -40°C \leq Tj \leq 125°C with bias conditions of V_{BIAS} (VCC, VBS) = 15V, CL = 1000 pF. The dynamic electrical characteristics are measured using the test definitions shown in Figure 3.

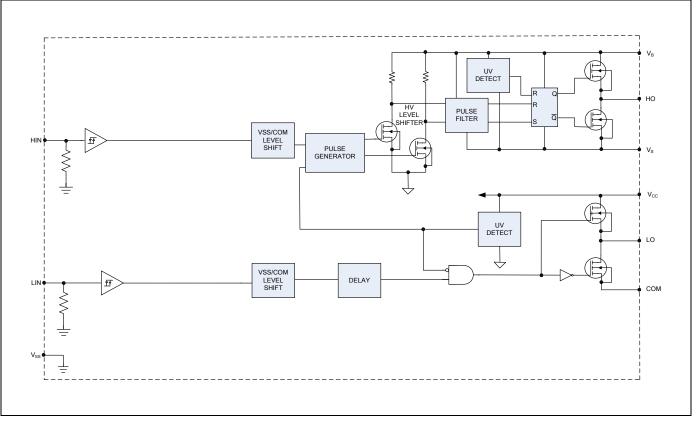
Symbol	Definition	Min	Тур	Max	Units	Test Conditions
t _{ON}	Turn-on propagation delay	50	90	175	ns	$V_{\rm S} = 0V$



AUIRS2191S

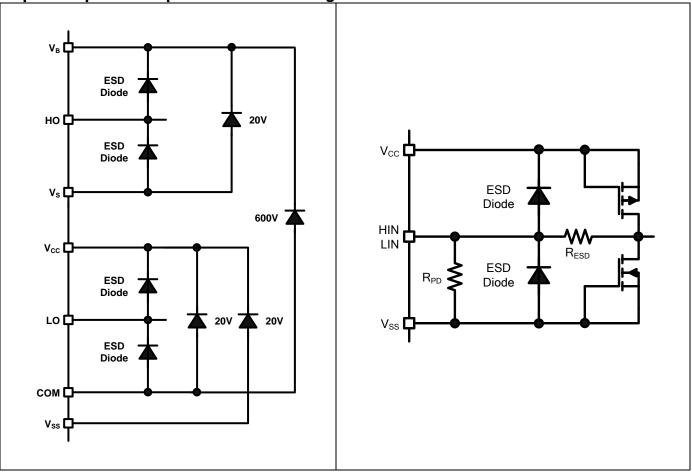
t _{OFF}	Turn-off propagation delay	50	90	175	V _S = 0V or 600V
t _R	Turn-on rise time	5	15	60	
t _F	Turn-off fall time	5	15	60	
MT	Delay matching, HS & LS turn-on/off			25	

Functional Block Diagram





Input/Output Pin Equivalent Circuit Diagrams: AUIRS2191

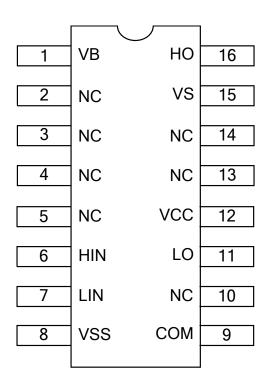




Lead Definitions: AUIRS2191

Pin#	Symbol	Description				
1	VB	High-side floating supply				
6	HIN	Logic inputs for high-side gate driver output (HO), in phase (referenced to V_{SS})				
7	LIN	ogic inputs for low-side gate driver output (LO), in phase (referenced to V _{SS})				
8	VSS	Low-side logic return				
9	COM	Low-side return				
11	LO	Low-side gate drive output				
12	VCC	Low-side supply voltage				
15	VS	High voltage floating supply return				
16	HO	High-side gate drive output				

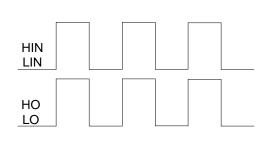
Lead Assignments



16 Lead SOIC



Application Information and Additional Details



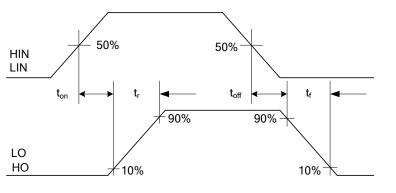


Figure 1. Input/Output Timing Diagram



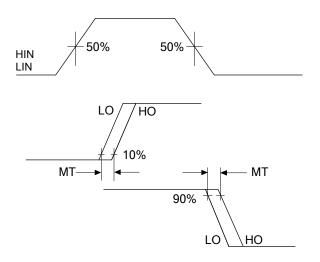


Figure 3. Delay Matching Waveform Definitions

Negative Vs Safety Operating Area (negVs SOA)

In normal switching operation the Vs node may fall below (i.e. negative) VSS/COM nodes (e.g. because of poor circuit layout and high dV/dt). This condition should be limited since it could bring to an uncontrolled behavior of the driver. The negVs SOA identifies the energy of negative Vs pulses which the driver can withstand; pulse energy is identified as the product of pulse duration by its amplitude. Fig. 7 shows the negVs SOA of AUIRS2191S at $T_A = -40C$, +25°C and +125C.

Test conditions were VCC=VBS=15V referenced to VSS=COM.

Even though the AUIRS2191S has been designed and tested to withstand these negative VS transient conditions, it is highly recommended that the circuit designer always limits the negative VS transients as much as possible by careful PCB layout and component use.

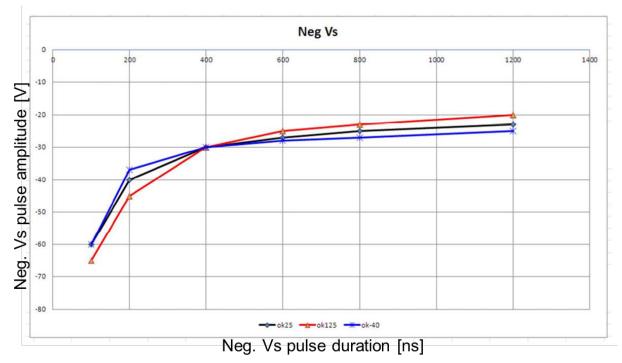


Figure 7: -Vs Transient results



Parameter Temperature Trends

20

18

16

14

12

-50

-25

0

25

Figure 6. Turn-On Rise Time vs. Temperature

Temperature (°C)

50

75

100

125

Torn-On Rise Time (ns)

Figures illustrated in this chapter provide information on the experimental performance of the AUIRS2191S HVIC. The line plotted in each figure is generated from actual lab data. A large number of individual samples were tested at three temperatures (-40 °C, 25 °C, and 125 °C) in order to generate the experimental curve. The line consists of three data points (one data point at each of the tested temperatures) that have been connected together to illustrate the understood trend. The individual data points on the Typ. curve were determined by calculating the averaged experimental value of the parameter (for a given temperature).

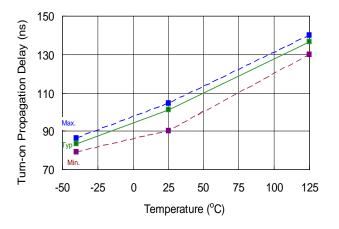
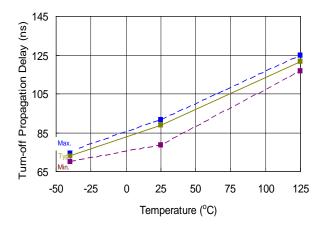


Figure 4. Turn-On Time vs. Temperature





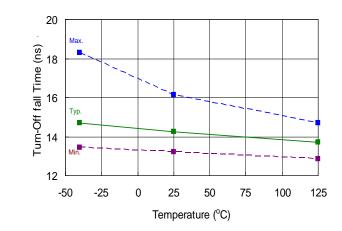


Figure 7. Turn-Off Fall Time vs. Temperature

AUIRS2191S



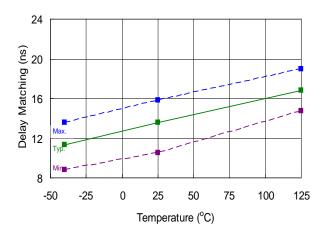


Figure 8. Delay Matching Time vs. Temperature

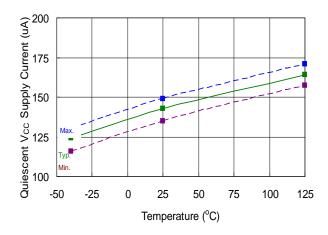


Figure 10. V_{cc} Supply Current vs. Temperature

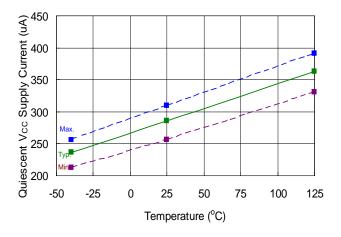


Figure 12. V_{CC} = 18V Supply Current vs. Temperature

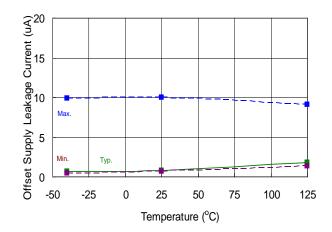


Figure 9. Offset Supply Current vs. Temperature

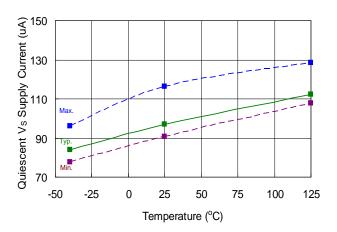


Figure 11. V_{BS} Supply Current vs. Temperature

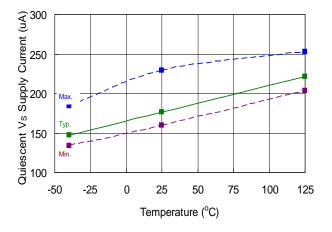


Figure 13. V_{BS} = 18V Supply Current vs. Temperature

AUIRS2191S



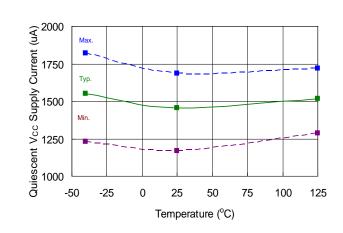


Figure 14. V_{CC} = 20V Supply Current vs. Temperature

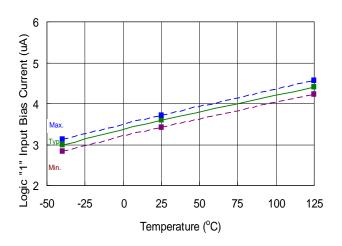


Figure 16. Logic "1" Input Bias Current vs. Temperature

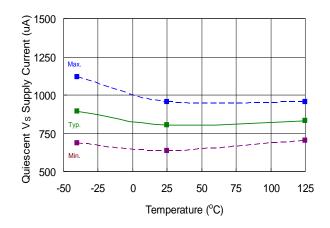


Figure 15. V_{BS} = 20V Supply Current vs. Temperature

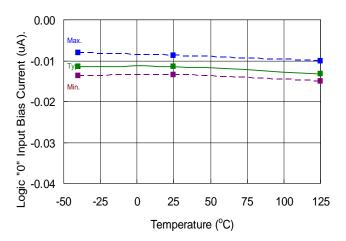
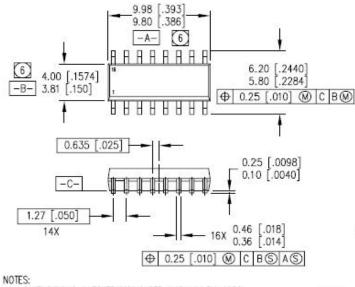


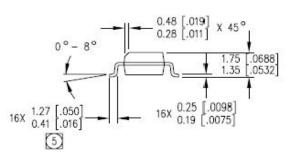
Figure 17. Logic "0" Input Bias Current vs. Temperature



Package Details: SOIC16N



- 1. DIMENSIONING & TOLERANCING PER ANSI Y14.5M-1982.
- 2. CONTROLLING DIMENSION: MILLIMETER
- 3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
- 4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-012AC.

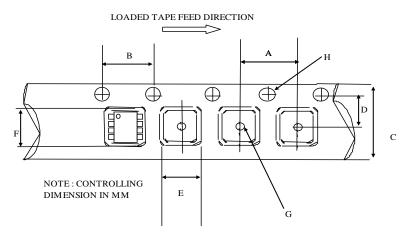


5 DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO A SUBSTRATE.

DIMENSION DOES NOT INCLUDE MOLD PROTUSIONS. MOLD PROTUSIONS SHALL NOT EXCEED 0.15 [.006].

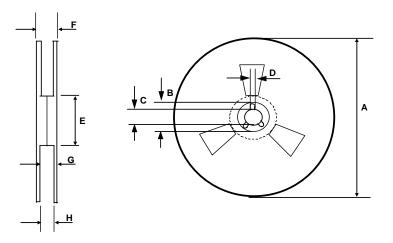
(6)

Package Details: SOIC16N, Tape and Reel



CARRIER TAPE DIMENSION FOR 16SOICN

	Metric		Imp	erial
Code	Min	Max	Min	Max
А	7.90	8.10	0.311	0.318
В	3.90	4.10	0.153	0.161
С	15.70	16.30	0.618	0.641
D	7.40	7.60	0.291	0.299
E	6.40	6.60	0.252	0.260
F	10.20	10.40	0.402	0.409
G	1.50	n/a	0.059	n/a
Н	1.50	1.60	0.059	0.062

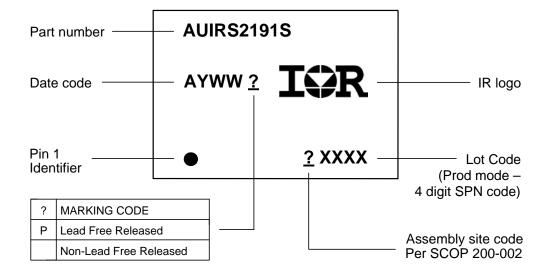


REEL DIMENSIONS FOR 16SOICN

	Metric		Imp	erial
Code	Min	Max	Min	Max
A	329.60	330.25	12.976	13.001
В	20.95	21.45	0.824	0.844
С	12.80	13.20	0.503	0.519
D	1.95	2.45	0.767	0.096
E	98.00	102.00	3.858	4.015
F	n/a	22.40	n/a	0.881
G	18.50	21.10	0.728	0.830
Н	16.40	18.40	0.645	0.724



Part Marking Information



Ordering Information

		Standard Pack		
Base Part Number	Package Type	Form	Quantity	Complete Part Number
		Tube/Bulk	45	AUIRS2191S
AUIRS2191S	SOIC16N	Tape and Reel	2500	AUIRS2191STR

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Revision History

Date	Comment
Feb. 5, 2009	Original document
Jan. 22, 2010	Added timing, Iqxx, input bias tri-temp graphs; updated min. timing parameter; updated actual part marking;
Jan. 27, 2010	lo+ and lo- unit corrected (from uA to A) Test condition changed (from 7V to 9.8V) in table of Stat el char, Vih and Vil. lqcc and lqbs specified also at 18V and at 20V of supply voltage. Tr and tf typ and max changed. Abs Max Rat: Vs Max changed from VB+20 to VB+0.3 Stat Elec Char: "IIN and IO parameters are referenced to COM" sentence modified in heading. I _o changed from 0 to 2 mA in V _{OH} and V _{OL} test conditions. I/O Pin Eq Cir Diag: clamp voltage values changed from 25V to 20V. Changed MT max to 25nS from 15nS; added temperature range spec: -40°C ≤ Tj ≤ 125°C on top of statics and dynamic electrical characteristics tables.
Feb. 01, 2010	Added typ. and max. value for lqcc_18, lqcc_20, lqbs_18, lqbs_20, and their tri-temp graphs; added guranteed by design note for IO+/-
Mar. 15, 2010	Added CDM ESD level to qual info page; Corrected Voh max. spec to 3.3V with test condition of I0=2mA.
May 26 th , 2010	I_{IN+} Typ and max change; Io+ and Io- min added; tR and tF max change; Iqcc20 max = 2500uA Ton max = 175ns, Toff max = 175ns.
Jun 08th 2011	V _{BSUV-} change from 9.0V down to 8.8V
Oct. 26, 2011	Added "Lead-Free and RoHS Compliant" to front page, updated latch up rating on qual info page; updated "Important Notice" with latest version 2.
Oct. 27, 2011	Added NTSOA
Jun. 11, 2012	V _{OH} parameter spitted into V _{OH 2mA} and V _{OH 20mA}
Oct 24th, 2012	negVs SOA change introducing tri-temp info.
Jan. 18, 2013	Page1: removed Plasma Display from typical application; Page 3 – removed "plasma display" from description statement; Page 4 –removed note II from qual information page
Nov 18th, 2013	

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